

Vishay Siliconix

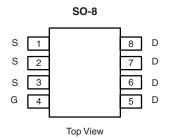
# P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)		
- 20	0.040 at V <sub>GS</sub> = - 4.5 V	- 6.2		
	0.060 at V <sub>GS</sub> = - 2.7 V	- 5.0		

#### FEATURES

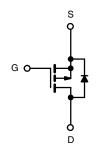
- Halogen-free According to IEC 61249-2-21
  Definition
- Compliant to RoHS Directive 2002/95/EC





Ordering Information: Si9433BDY-T1-E3 (Lead (Pb)-free)

Si9433BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b> T <sub>A</sub> = 25 °C, unless otherwise noted					
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	- 20		v
Gate-Source Voltage	Source Voltage		± 12		v
	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	- 6.2	- 4.5	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		- 5.0	- 3.5	
Pulsed Drain Current		I <sub>DM</sub>	- 20		A
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	- 2.3	- 1.2	
	T <sub>A</sub> = 25 °C	Р	2.5	1.3	14/
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	P <sub>D</sub>	1.6	0.8	W
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	P	45	50	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	R <sub>thJA</sub>	80	95	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	20	24	

Notes:

a. Surface Mounted on FR4 board, t  $\leq$  10 s.

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						•		
<b>SPECIFICATIONS</b> $T_1 = 25 \text{ °C}$ , unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Typ. <sup>a</sup>	Max.	Unit		
Static								
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -250 \ \mu A$	- 0.6		- 1.5	V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			± 100	nA		
Zero Gate Voltage Drain Current	lana	$V_{DS} = -20 V, V_{GS} = 0 V$			- 1			
	IDSS	$V_{DS}$ = - 20 V, $V_{GS}$ = 0 V, $T_{J}$ = 70 °C			- 10	μΑ		
Our Ohada Davia Ohamanth	1	$V_{DS} \leq$ - 5 V, $V_{GS}$ = - 4.5 V	$_{\rm S} \le -5$ V, V <sub>GS</sub> = -4.5 V - 20			A		
On-State Drain Current <sup>b</sup>	I <sub>D(on)</sub>	$V_{DS} \le$ - 5 V, $V_{GS}$ = - 2.7 V	- 5					
Drain-Source On-State Resistance <sup>b</sup>	D	V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 6.2 A		0.030	0.040	0		
	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 2.7 V, I <sub>D</sub> = - 5.0 A		0.050	0.060	Ω		
Forward Transconductance <sup>b</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 9 V, I <sub>D</sub> = - 6.2 A		15		S		
Diode Forward Voltage <sup>b</sup>	V <sub>SD</sub>	I <sub>S</sub> = - 2.6 A, V <sub>GS</sub> = 0 V		- 0.76	- 1.1	V		
Dynamic <sup>a</sup>								
Total Gate Charge	Qg			8.8	14			
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -6 V, V_{GS} = -4.5 V, I_D = -6.2 A$ 1.8		1.8		nC		
Gate-Drain Charge	Q <sub>gd</sub>			2.4				
Gate Resistance	Rg			8.5		Ω		
Turn-On Delay Time	t <sub>d(on)</sub>			40	60			
Rise Time	t <sub>r</sub>	$V_{DD}$ = - 6 V, $R_L$ = 6 $\Omega$		55	85			
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_{\text{D}}\cong$ - 1 A, $\text{V}_{\text{GEN}}$ = - 4.5 V, $\text{R}_{\text{g}}$ = 6 $\Omega$		65	100	ns		
Fall Time	t <sub>f</sub>			30	45	]		
Source-Drain Reverse Recovery Time t <sub>rr</sub> I <sub>F</sub> = - 2.		I <sub>F</sub> = - 2.3 A, dl/dt = 100 A/μs		35	55			

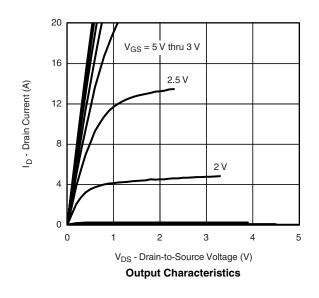
Notes:

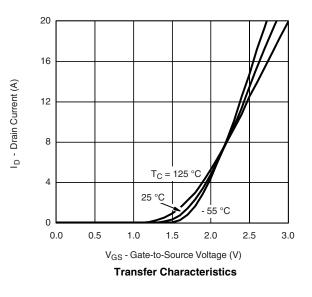
a. For design aid only; not subject to production testing.

b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

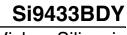
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





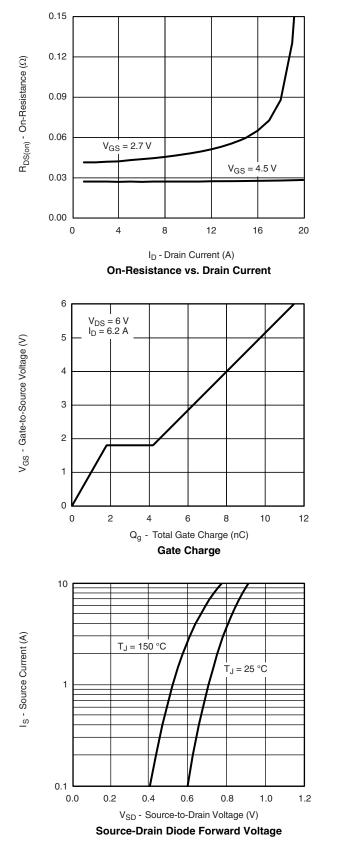
SHA

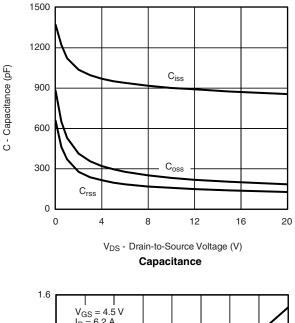


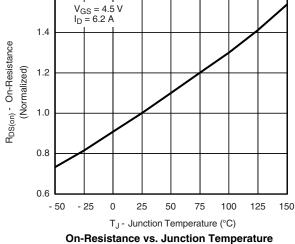
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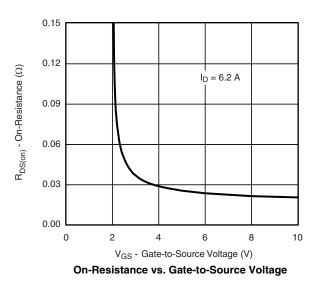
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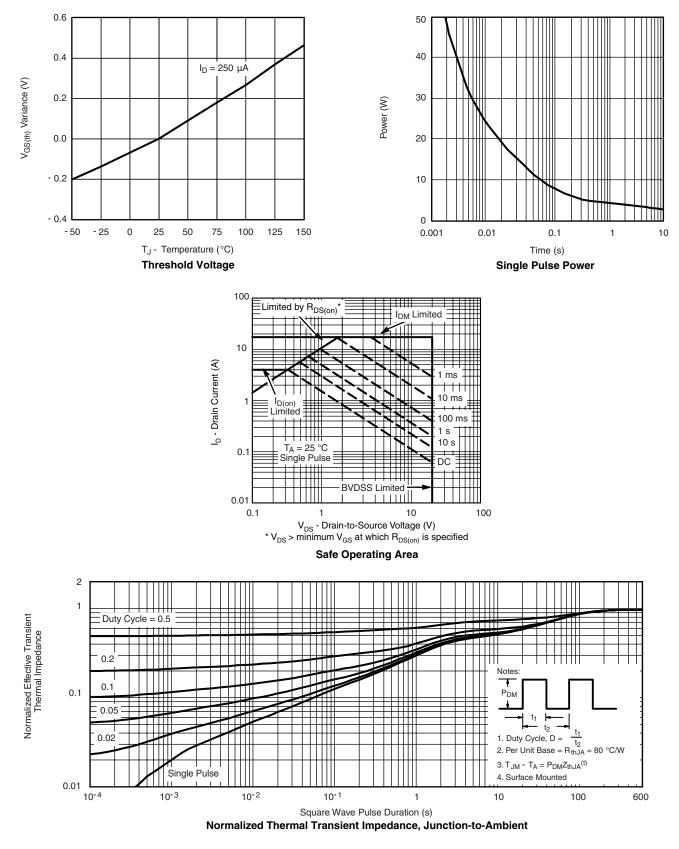


Document Number: 72755 S09-0870-Rev. B, 18-May-09

# Si9433BDY

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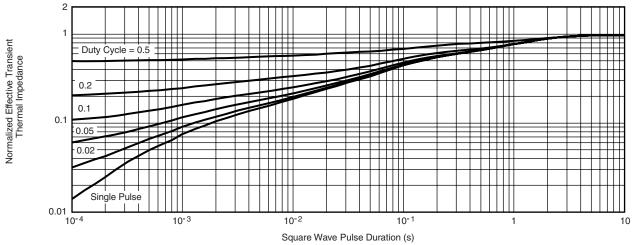
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Si9433BDY

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#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

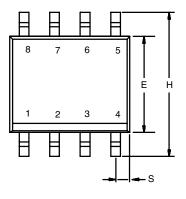
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg272755">www.vishay.com/ppg272755</a>.



# Package Information

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# SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





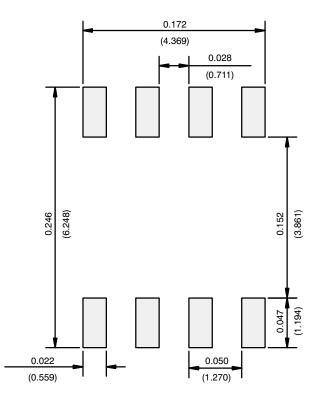
	MILLIM	IETERS	INCHES		
DIM	Min	Мах	Min	Max	
A	1.35	1.75	0.053	0.069	
A <sub>1</sub>	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27	BSC	0.050 BSC		
н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498					

# **Application Note 826**

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**RECOMMENDED MINIMUM PADS FOR SO-8** 



Recommended Minimum Pads Dimensions in Inches/(mm)

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